

BLP8G10S-270PW

Power LDMOS transistor

Rev. 2 — 1 October 2015

AMMPLION

Product data sheet

1. Product profile

1.1 General description

270 W LDMOS packaged symmetric Doherty power transistor for base station applications at frequencies from 700 MHz to 900 MHz.

Table 1. Typical performance

Typical RF performance at $T_{case} = 25\text{ °C}$ in a Doherty application test circuit. $V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$ (main); $V_{GS(amp)peak} = 0.5\text{ V}$, unless otherwise specified.

Test signal	f	V_{DS}	$P_{L(AV)}$	G_p	η_D	ACPR
	(MHz)	(V)	(dBm)	(dB)	(%)	(dBc)
1-carrier W-CDMA	716 to 768	28	47.5	17.3	46	-35 [1]

[1] Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.65 dB at 0.01% probability on CCDF per carrier.

1.2 Features and benefits

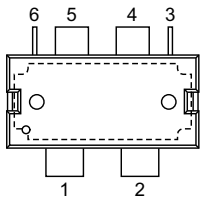
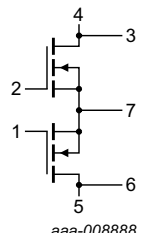
- Excellent ruggedness
- High-efficiency
- Low thermal resistance providing excellent thermal stability
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent digital pre-distortion capability
- Internally matched for ease of use
- Integrated ESD protection
- Bias through video leads
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

- RF power amplifiers for base stations and multi carrier applications in the 700 MHz to 900 MHz frequency range

2. Pinning information

Table 2. Pinning

Pin	Description	Simplified outline	Graphic symbol
1, 2	gate		 aaa-008888
3, 6	bias/video decoupling		
4, 5	drain		
7	source [1]		

[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
BLP8G10S-270PW	HSOP6F	plastic, heatsink small outline package; 6 leads (flat)	SOT1221-2

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DS}	drain-source voltage		-	65	V
$V_{GS(amp)main}$	main amplifier gate-source voltage		-0.5	+13	V
$V_{GS(amp)peak}$	peak amplifier gate-source voltage		-0.5	+13	V
T_{stg}	storage temperature		-65	+150	°C
T_j	junction temperature	[1]	-	225	°C

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

Symbol	Parameter	Conditions	Typ	Unit
$R_{th(j-c)}$	thermal resistance from junction to case	$V_{DS} = 28\text{ V}$; $I_{Dq} = 650\text{ mA}$ (main); $V_{GS(amp)peak} = 0.5\text{ V}$; $T_{case} = 80\text{ °C}$;		
		$P_L = 56\text{ W}$	0.50	K/W
		$P_L = 89\text{ W}$	0.43	K/W

6. Characteristics

Table 6. DC characteristics

Per section; $T_j = 25\text{ °C}$ unless otherwise specified.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{(BR)DSS}$	drain-source breakdown voltage	$V_{GS} = 0\text{ V}; I_D = 2.25\text{ mA}$	65	-	-	V
$V_{GS(th)}$	gate-source threshold voltage	$V_{DS} = 10\text{ V}; I_D = 225\text{ mA}$	1.5	1.9	2.3	V
V_{GSq}	gate-source quiescent voltage	$V_{DS} = 28\text{ V}; I_D = 1000\text{ mA}$	1.7	2.1	2.5	V
I_{DSS}	drain leakage current	$V_{GS} = 0\text{ V}; V_{DS} = 28\text{ V}$	-	-	1.4	μA
I_{DSX}	drain cut-off current	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; V_{DS} = 10\text{ V}$	-	37.5	-	A
I_{GSS}	gate leakage current	$V_{GS} = 11\text{ V}; V_{DS} = 0\text{ V}$	-	-	140	nA
g_{fs}	forward transconductance	$V_{DS} = 10\text{ V}; I_D = 11.25\text{ mA}$	-	14	-	S
$R_{DS(on)}$	drain-source on-state resistance	$V_{GS} = V_{GS(th)} + 3.75\text{ V}; I_D = 7875\text{ mA}$	-	90	148	$\text{m}\Omega$

Table 7. RF characteristics

Test signal: 1-carrier W-CDMA; 3GPP test model 1; 64 DPCH; PAR = 9.65 dB at 0.01 % probability on the CCDF per carrier; $f_1 = 718.5\text{ MHz}; f_2 = 765.5\text{ MHz}$; RF performance at $V_{DS} = 28\text{ V}$;

$I_{Dq} = 2000\text{ mA}$ (main); $T_{case} = 25\text{ °C}$; unless otherwise specified; in a class AB production test circuit at frequencies from 716 MHz to 768 MHz.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
G_p	power gain	$P_{L(AV)} = 56\text{ W}$	19	20	-	dB
RL_{in}	input return loss	$P_{L(AV)} = 56\text{ W}$	-	-16	-12	dB
η_D	drain efficiency	$P_{L(AV)} = 56\text{ W}$	25	29	-	%
ACPR	adjacent channel power ratio	$P_{L(AV)} = 56\text{ W}$	-	-38	-33	dBc

Table 8. RF characteristics

Test signal: pulsed RF; $f_1 = 718.5\text{ MHz}; f_2 = 756.5\text{ MHz}; t_p = 10\text{ ms}; \delta = 10\%$; RF performance at $V_{DS} = 28\text{ V}; I_{Dq} = 2000\text{ mA}$ (main); $T_{case} = 25\text{ °C}$; unless otherwise specified; in a class-AB narrow band production circuit.

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$P_{L(3dB)}$	output power at 3 dB gain compression		315	365	-	W

7. Application information

7.1 Application circuit

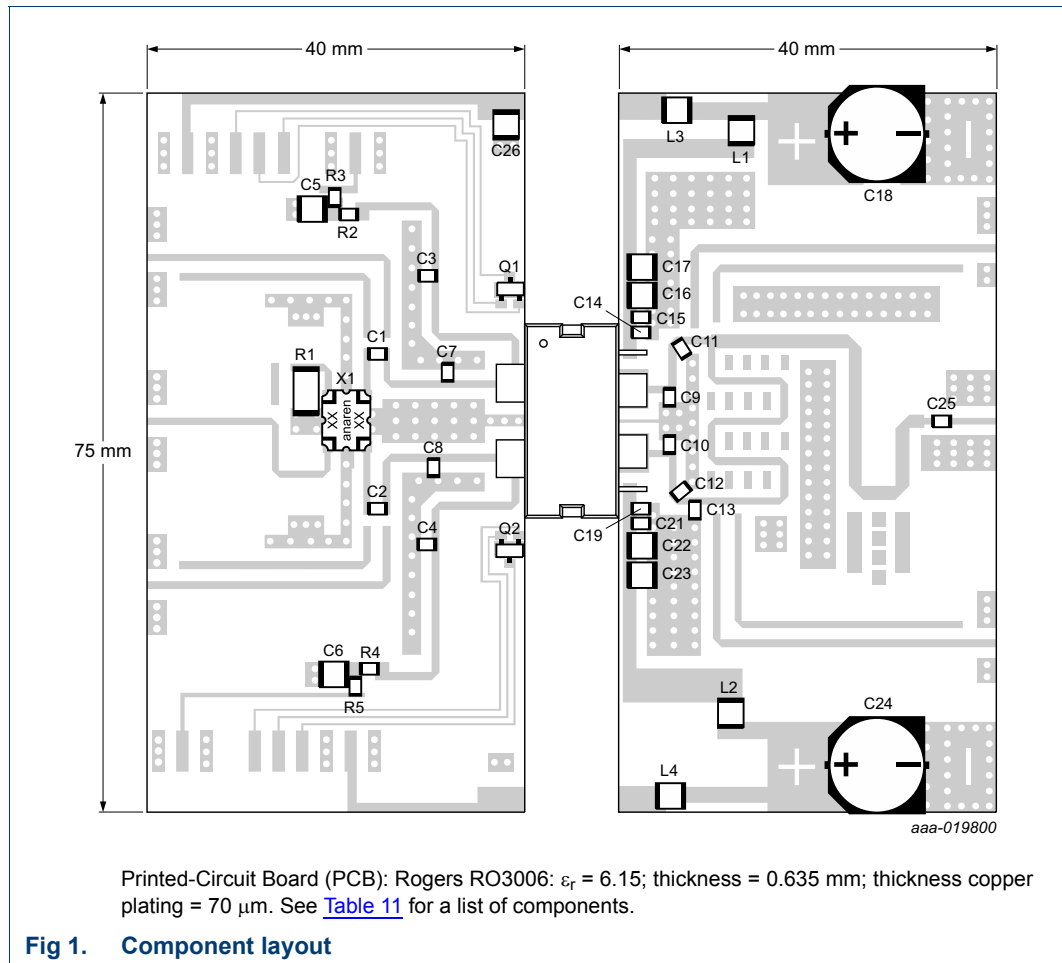


Fig 1. Component layout

Table 9. List of components

See [Figure 15](#) for component layout.

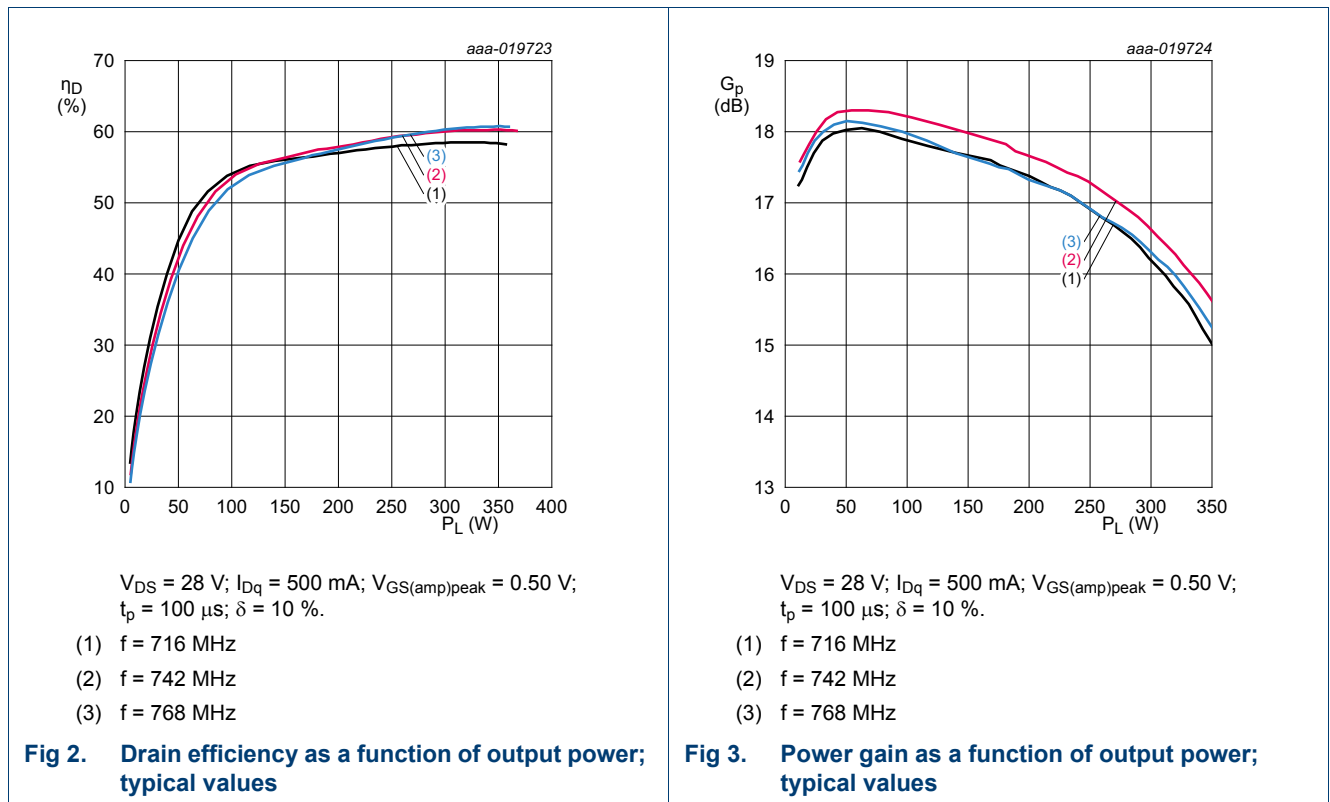
Component	Description	Value	Remarks
C1, C2, C3, C4, C14, C19, C25	multilayer ceramic chip capacitor	82 pF	ATC 600F
C5, C6, C16, C17, C22, C23, C26	multilayer ceramic chip capacitor	10 μF	Murata: GRM32ER71H106KA12
C7, C8, C9, C10	multilayer ceramic chip capacitor	15 pF	ATC 600F
C11, C12	multilayer ceramic chip capacitor	5.6 pF	ATC 600F
C13	multilayer ceramic chip capacitor	1.8 pF	ATC 600F
C15, C21	multilayer ceramic chip capacitor	1 μF	Murata: GRM31CR72A105KA01L
C18, C24	electrolytic capacitor	2200 μF	Multicomp: MCGPR35V228M16X32
L1, L2, L3, L4	chip ferrite bead	-	Murata; BLE32PN300SN1L
Q1, Q2	transistor	-	Fairchild: MMBT2222
R1	resistor	50 Ω	Panasonic: ERJ-L14KF50MU
R2, R4	resistor	1.1 k Ω	Vishay Dale

Table 9. List of components
See [Figure 15](#) for component layout.

Component	Description	Value	Remarks
R3	resistor	1.2 kΩ	Vishay Dale
R5	resistor	3.9 kΩ	Vishay Dale
X1	hybrid coupler	3 dB, 90°	Anaren: X3C07P1-03S

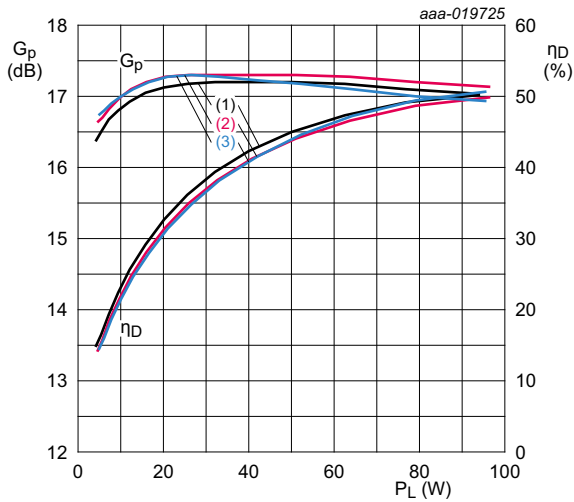
7.2 Graphical data measured at frequency band from 716 MHz to 768 MHz

7.2.1 Pulsed CW



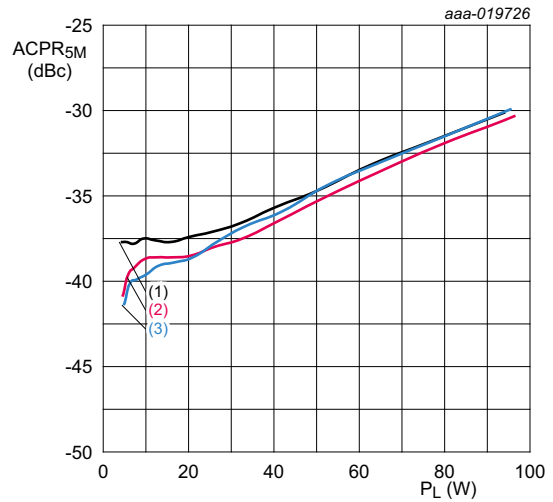
7.2.2 1-Carrier W-CDMA

PAR = 9.7 dB per carrier at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (100 % clipping).



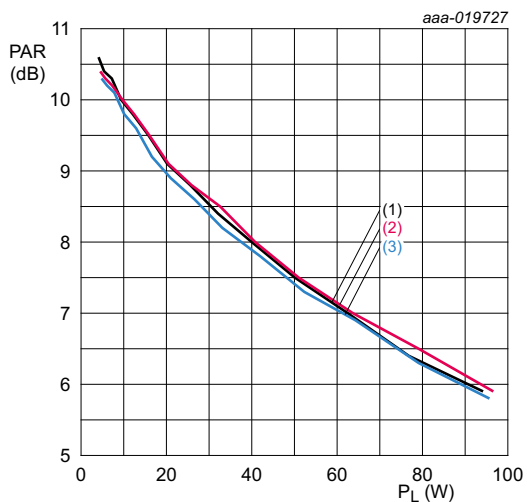
$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

Fig 4. Power gain and drain efficiency as function of output power; typical values



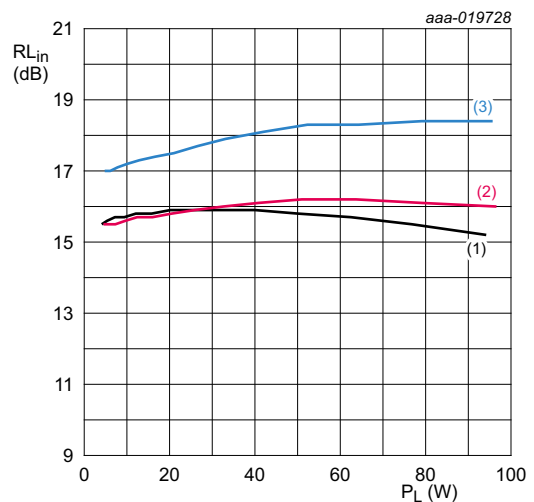
$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

Fig 5. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

Fig 6. Peak-to-average power ratio as a function of output power; typical values

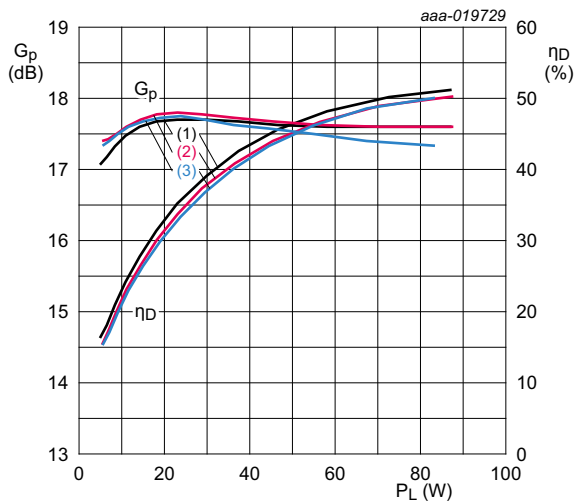


$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

Fig 7. Input return loss as a function of output power; typical values

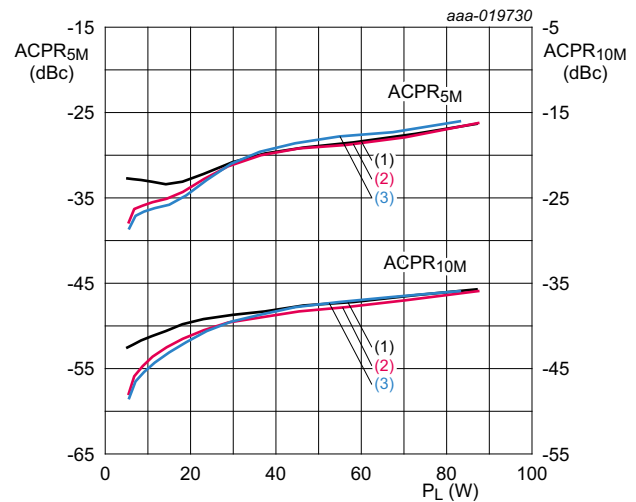
7.2.3 2-Carrier W-CDMA

PAR = 8.4 dB at 0.01 % probability on the CCDF; 3GPP test model 1 with 64 DPCH (46 % clipping).



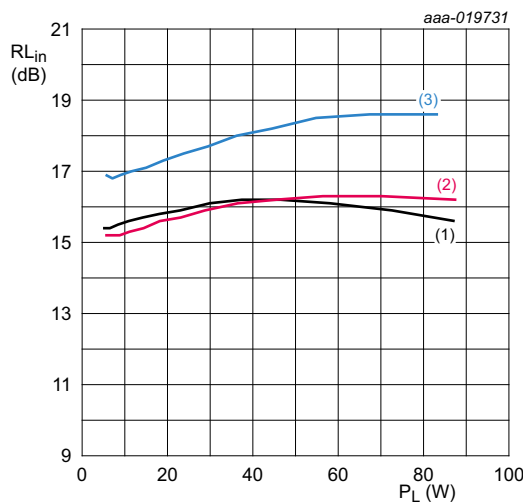
$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

Fig 8. Power gain and drain efficiency as function of output power; typical values



$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

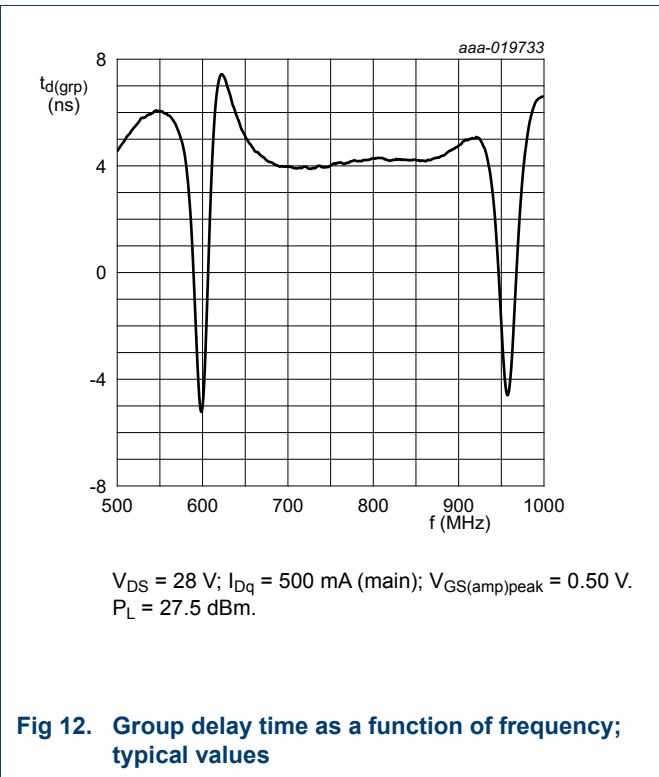
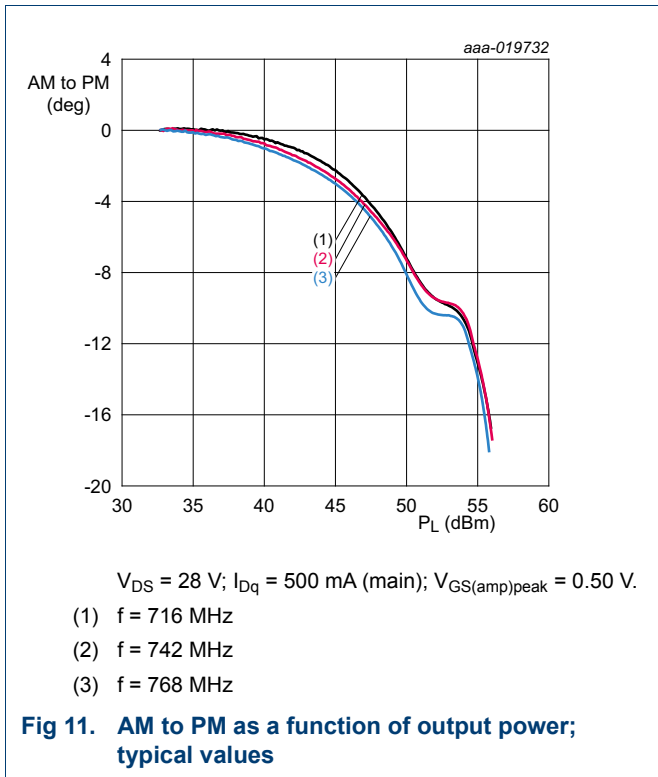
Fig 9. Adjacent channel power ratio (5 MHz) and adjacent channel power ratio (10 MHz) as function of output power; typical values



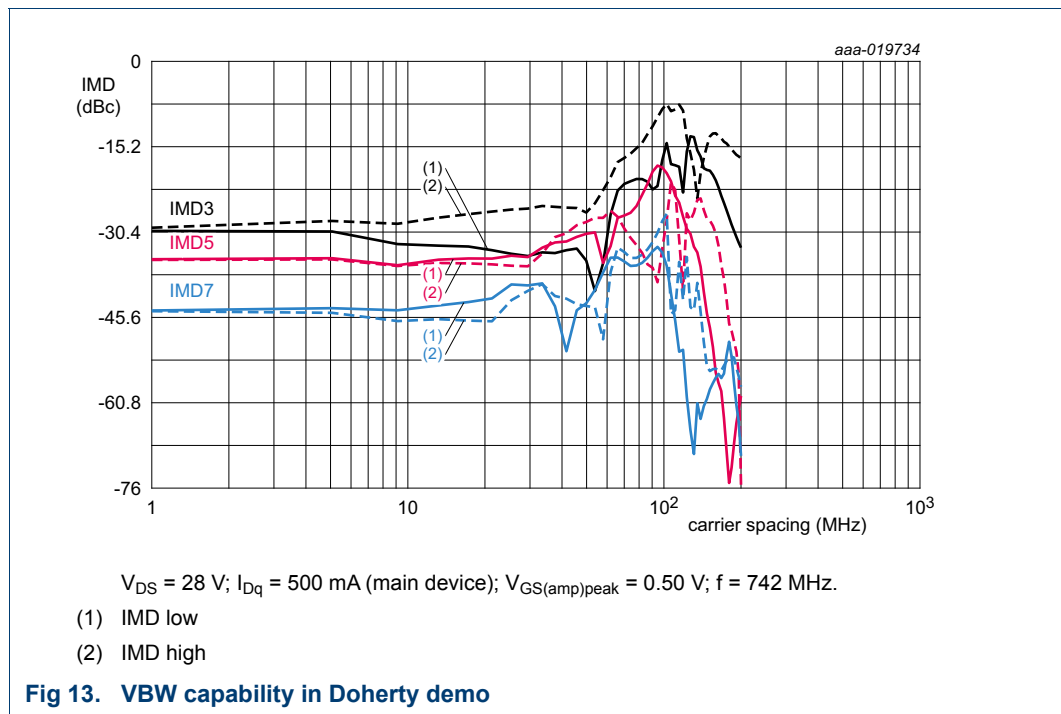
$V_{DS} = 28\text{ V}$; $I_{Dq} = 500\text{ mA}$; $V_{GS(amp)peak} = 0.50\text{ V}$.
 (1) $f = 716\text{ MHz}$
 (2) $f = 742\text{ MHz}$
 (3) $f = 768\text{ MHz}$

Fig 10. Input return loss as a function of output power; typical values

7.2.4 CW



7.2.5 2-Tone VBW



8. Test information

8.1 Ruggedness in Doherty operation

The BLP8G10S-270PW is capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: $V_{DS} = 28\text{ V}$; $I_{Dq} = 2000\text{ mA}$; $f = 719\text{ MHz}$. Test signal: 1-carrier W-CDMA; $P_L = 85\text{ W}$ (5 dB OBO); 100 % clipping

8.2 Impedance information

Table 10. Typical impedance of main or peak device

Measured load-pull data of main device; $I_{Dq} = 700\text{ mA}$ (main); $V_{DS} = 28\text{ V}$; pulsed CW ($t_p = 100\text{ }\mu\text{s}$; $\delta = 10\%$).

f (MHz)	Z_S [1] (Ω)	Z_L [1] (Ω)	P_L [2] (W)	η_D [2] (%)	G_p [2] (dB)
Maximum power load					
728	3.1 – j0.8	1.3 – j2.0	261.2	60.0	17.3
748	3.1 – j1.1	1.3 – j1.9	258.6	60.6	17.3
768	3.1 – j1.4	1.3 – j1.9	252.1	60.3	17.4
869	4.4 – j2.2	1.4 – j2.6	240.6	60.1	17.3
880	4.7 – j2.3	1.3 – j2.6	237.3	59.9	17.3
894	5.1 – j2.0	1.3 – j2.6	235.9	60.5	17.3
Maximum drain efficiency load					
728	3.1 – j0.8	3.5 – j1.1	164.7	73.4	20.0
748	3.1 – j1.1	3.5 – j0.7	150.3	73.2	20.2
768	3.1 – j1.4	3.2 – j0.7	150.3	72.2	20.0
869	4.4 – j2.2	2.4 – j1.0	141.9	71.4	19.8
880	4.7 – j2.3	2.4 – j1.0	136.7	70.4	19.7
894	5.1 – j2.0	2.0 – j1.4	155.9	70.3	19.3

[1] Z_S and Z_L defined in [Figure 14](#).

[2] At 3 dB gain compression.

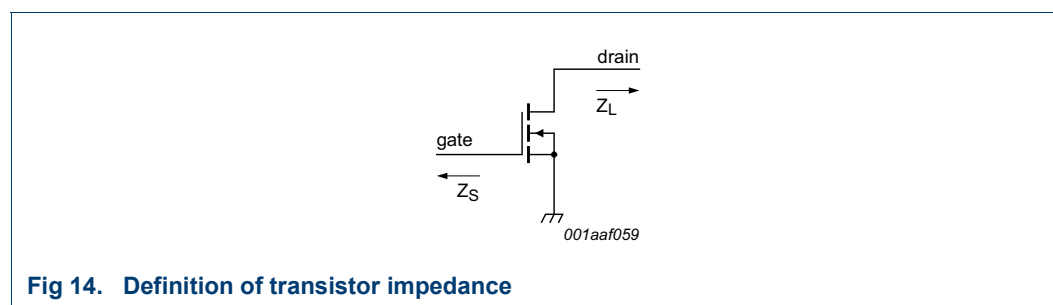


Fig 14. Definition of transistor impedance

8.3 Test circuit

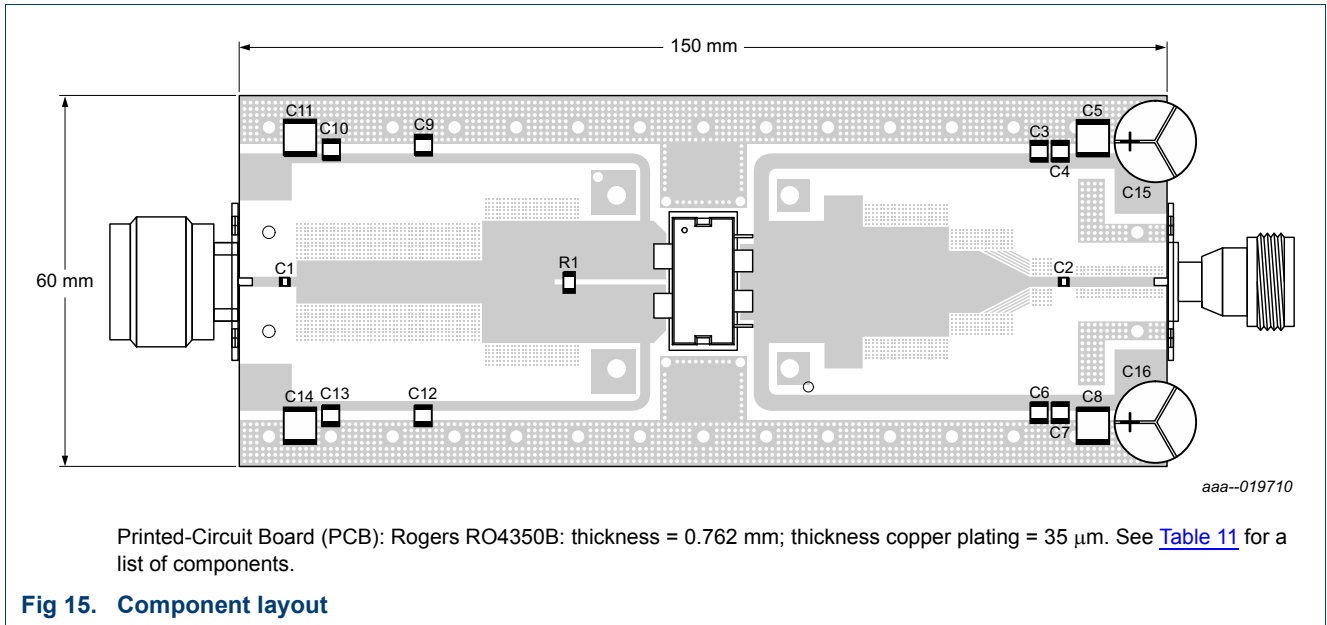


Table 11. List of components

See [Figure 15](#) for component layout.

Component	Description	Value	Remarks
C1, C3, C6, C9, C12	multilayer ceramic chip capacitor	82 pF	[1] ATC 800B
C2	multilayer ceramic chip capacitor	180 pF	[1] ATC 800B
C4, C7, C10, C13	multilayer ceramic chip capacitor	1 μF	[2] Murata
C5, C8, C11, C14	multilayer ceramic chip capacitor	10 μF, 50 V	[2] Murata
C15, C16	electrolytic capacitor	2200 μF, 63 V	
R1	resistor	5 kΩ	SMD 1206

[1] American Technical Ceramics type 800B or capacitor of same quality.

[2] Murata or capacitor of same quality.

9. Package outline

HSOP6F: plastic, heatsink small outline package; 6 leads(flat)

SOT1221-2

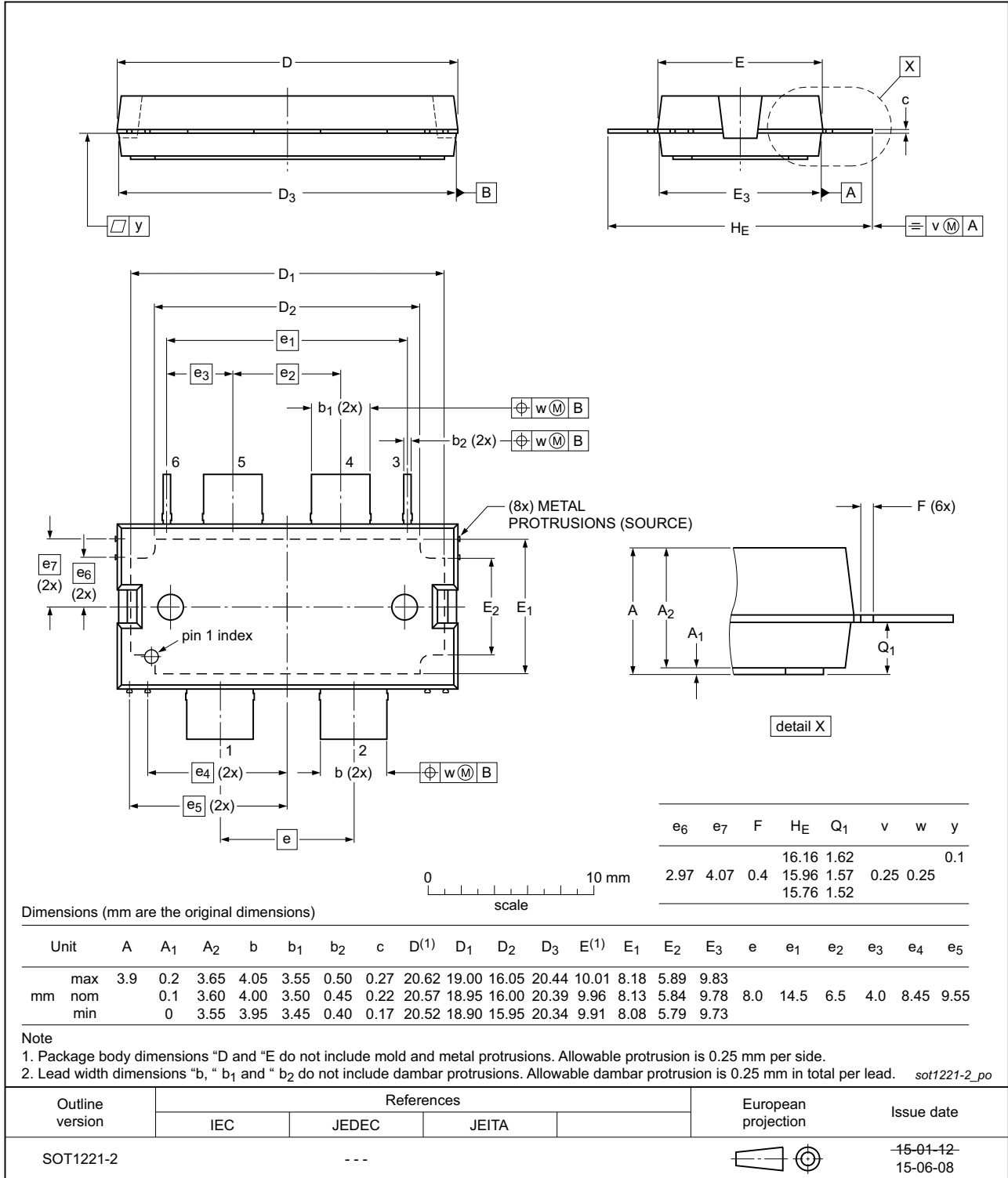


Fig 16. Package outline SOT1221-2 (HSOP6F)

10. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the *ANSI/ESD S20.20*, *IEC/ST 61340-5*, *JESD625-A* or equivalent standards.

11. Abbreviations

Table 12. Abbreviations

Acronym	Description
3GPP	3rd Generation Partnership Project
AM	Amplitude Modulation
CCDF	Complementary Cumulative Distribution Function
CW	Continuous Wave
DPCH	Dedicated Physical CHannel
ESD	ElectroStatic Discharge
LDMOS	Laterally Diffused Metal-Oxide Semiconductor
MTF	Median Time to Failure
OBO	Output Back-Off
PAR	Peak-to-Average Ratio
PM	Phase Modulation
SMD	Surface Mounted Device
VBW	Video Bandwidth
VSWR	Voltage Standing Wave Ratio
W-CDMA	Wideband Code Division Multiple Access

12. Revision history

Table 13. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BLP8G10S-270PW v.2	20151001	Product data sheet	-	BLP8G10S-270PW v.1
Modifications:	<ul style="list-style-type: none"> The format of this document has been redesigned to comply with the new identity guidelines of Ampleon Legal texts have been adapted to the new company name where appropriate 			
BLP8G10S-270PW v.1	20150917	Product data sheet	-	-

13. Legal information

13.1 Data sheet status

Document status ^{[1][2]}	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL <http://www.ampleon.com>.

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For sales office addresses, please visit: <http://www.ampleon.com/sales>

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